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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details

Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	192000
Total RAM Bits	13619200
Number of I/O	364
Number of Gates	-
Voltage - Supply	0.97V ~ 1.08V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	784-BBGA, FCBGA
Supplier Device Package	784-FCBGA (29x29)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/mpf200t-1fcg784i

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Parameter	Symbol	Min	Typ	Max	Unit
Transceiver TX and RX lanes supply at 1.05 V mode (when any lane rate is greater than 10.3125 Gbps) ¹	V _{DDA}	1.02	1.05	1.08	V
Programming and HSIO receiver supply	V _{DD18}	1.71	1.80	1.89	V
FPGA core and FPGA PLL high-voltage supply	V _{DD25}	2.425	2.50	2.575	V
Transceiver PLL high-voltage supply	V _{DDA25}	2.425	2.50	2.575	V
Transceiver reference clock supply –3.3 V nominal	V _{DD_XCVR_CLK}	3.135	3.3	3.465	V
Transceiver reference clock supply –2.5 V nominal	V _{DD_XCVR_CLK}	2.375	2.5	2.625	V
Global V _{REF} for transceiver reference clocks ³	XCVR _{VREF}	Ground		V _{DD_XCVR_CLK}	V
HSIO DC I/O supply. Allowed nominal options: 1.2 V, 1.35 V, 1.5 V, and 1.8 V ⁴	V _{DDI_x}	1.14	Various	1.89	V
GPIO DC I/O supply. Allowed nominal options: 1.2 V, 1.5 V, 1.8 V, 2.5 V, and 3.3 V ^{2,4}	V _{DDI_x}	1.14	Various	3.465	V
Dedicated I/O DC supply for JTAG and SPI (GPIO Bank 3). Allowed nominal options: 1.8 V, 2.5 V, and 3.3 V	V _{DDI₃}	1.71	Various	3.465	V
GPIO auxiliary supply for I/O bank x with V _{DDI_x} = 3.3 V nominal ^{2,4}	V _{DDAU_x}	3.135	3.3	3.465	V
GPIO auxiliary supply for I/O bank x with V _{DDI_x} = 2.5 V nominal or lower ^{2,4}	V _{DDAU_x}	2.375	2.5	2.625	V
Extended commercial temperature range	T _J	0		100	°C
Industrial temperature range	T _J	-40		100	°C
Extended commercial programming temperature range	T _{PRG}	0		100	°C
Industrial programming temperature range	T _{PRG}	-40		100	°C

1. V_{DD} and V_{DDA} can independently operate at 1.0 V or 1.05 V nominal. These supplies are not dynamically adjustable.
2. For GPIO buffers where I/O bank is designated as bank number, if V_{DDI_x} is 2.5 V nominal or 3.3 V nominal, V_{DDAU_x} must be connected to the V_{DDI_x} supply for that bank. If V_{DDI_x} for a given GPIO bank is <2.5 V nominal, V_{DDAU_x} per I/O bank must be powered at 2.5 V nominal.
3. XCVR_{VREF} globally sets the reference voltage of the transceiver's single-ended reference clock input buffers. It is typically near V_{DD_XCVR_CLK}/2 V but is allowed in the specified range.
4. The power supplies for a given I/O bank x are shown as V_{DDI_x} and V_{DDAU_x}.

I/O Standard	Bank Type	VICM RANGE Libero Setting	V _{ICM^{1,3}} Min (V)	V _{ICM^{1,3}} Typ (V)	V _{ICM^{1,3}} Max (V)	V _{ID²} Min (V)	V _{ID} Typ (V)	V _{ID} Max (V)
LVDS18	HSIO	Low	0.05	0.4	0.8	0.1	0.35	0.6
		Mid (default)	0.6	1.25	1.65	0.1	0.35	0.6
LCMDS33	GPIO	Low	0.05	0.4	0.8	0.1	0.35	0.6
		Mid (default)	0.6	1.25	2.35	0.1	0.35	0.6
LCMDS18	HSIO	Low	0.05	0.4	0.8	0.1	0.35	0.6
		Mid (default)	0.6	1.25	1.65	0.1	0.35	0.6
LCMDS25	GPIO	Low	0.05	0.4	0.8	0.1	0.35	0.6
		Mid (default)	0.6	1.25	2.35	0.1	0.35	0.6
RSDS33	GPIO	Low	0.05	0.4	0.8	0.1	0.2	0.6
		Mid (default)	0.6	1.25	2.35	0.1	0.2	0.6
RSDS25	GPIO	Low	0.05	0.4	0.8	0.1	0.2	0.6
		Mid (default)	0.6	1.25	2.35	0.1	0.2	0.6
RSDS18 ⁵	HSIO	Low	0.05	0.4	0.8	0.1	0.2	0.6
		Mid (default)	0.6	1.25	1.65	0.1	0.2	0.6
MINILVDS33	GPIO	Low	0.05	0.4	0.8	0.1	0.3	0.6
		Mid (default)	0.6	1.25	2.35	0.1	0.3	0.6
MINILVDS25	GPIO	Low	0.05	0.4	0.8	0.1	0.3	0.6
		Mid (default)	0.6	1.25	2.35	0.1	0.3	0.6
MINILVDS18 ⁵	HSIO	Low	0.05	0.4	0.8	0.1	0.3	0.6
		Mid (default)	0.6	1.25	1.65	0.1	0.3	0.6
SUBLVDS33	GPIO	Low	0.05	0.4	0.8	0.1	0.15	0.3
		Mid (default)	0.6	0.9	2.35	0.1	0.15	0.3
SUBLVDS25	GPIO	Low	0.05	0.4	0.8	0.1	0.15	0.3
		Mid (default)	0.6	0.9	2.35	0.1	0.15	0.3
SUBLVDS18 ⁵	HSIO	Low	0.05	0.4	0.8	0.1	0.15	0.3
		Mid (default)	0.6	0.9	1.65	0.1	0.15	0.3
PPDS33	GPIO	Low	0.05	0.4	0.8	0.1	0.2	0.6
		Mid (default)	0.6	0.8	2.35	0.1	0.2	0.6
PPDS25	GPIO	Low	0.05	0.4	0.8	0.1	0.2	0.6
		Mid (default)	0.6	0.8	2.35	0.1	0.2	0.6
PPDS18 ⁵	HSIO	Low	0.05	0.4	0.8	0.1	0.2	0.6
		Mid (default)	0.6	0.8	1.65	0.1	0.2	0.6
SLVS33 ⁶	GPIO	Low	0.05	0.2	0.8	0.1	0.2	0.3
		Mid (default)	0.6	1.25	2.35	0.1	0.2	0.3
SLVS25 ⁶	GPIO	Low	0.05	0.2	0.8	0.1	0.2	0.3
		Mid (default)	0.6	1.25	2.35	0.1	0.2	0.3
SLVS18 ⁵	HSIO	Low	0.05	0.4	0.8	0.1	0.2	0.3
		Mid (default)	0.6	1.00	1.65	0.1	0.2	0.3
HCSL33 ⁶	GPIO	Low	0.05	0.35	0.8	0.1	0.55	1.1
		Mid (default)	0.6	1.25	2.35	0.1	0.55	1.1

I/O Standard	Bank Type	V _{O_{CM}} ¹ Min (V)	V _{O_{CM}} Typ (V)	V _{O_{CM}} Max (V)	V _{O_D} ² Min (V)	V _{O_D} ² Typ (V)	V _{O_D} ² Max (V)
MILVDS25 ³	GPIO		1.25		0.396	0.442	0.453
LVPECLE33 ³	GPIO		1.65		0.664	0.722	0.755
MIPIE25 ³	GPIO		0.25		0.1	0.22	0.3

1. V_{O_{CM}} is the output common mode voltage.
2. V_{O_D} is the output differential voltage.
3. Emulated output only.

6.3.3 Complementary Differential DC Input and Output Levels

The following tables list the complementary differential DC I/O levels.

Table 16 • Complementary Differential DC Input Levels

I/O Standard	V _{DDI} Min (V)	V _{DDI} Typ (V)	V _{DDI} Max (V)	V _{I_{CM}} ^{1,3} Min (V)	V _{I_{CM}} ^{1,3} Typ (V)	V _{I_{CM}} ^{1,3} Max (V)	V _{I_D} ² Min (V)	V _{I_D} Max (V)
SSTL25I	2.375	2.5	2.625	1.164	1.250	1.339	0.1	
SSTL25II	2.375	2.5	2.625	1.164	1.250	1.339	0.1	
SSTL18I	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
SSTL18II	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
SSTL15I	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
SSTL15II	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
SSTL135I	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
SSTL135II	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
HSTL15I	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
HSTL15II	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
HSTL135I	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
HSTL135II	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
HSTL12I	1.14	1.2	1.26	0.559	0.600	0.643	0.1	
HSUL18I	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
HSUL18II	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
HSUL12I	1.14	1.2	1.26	0.559	0.600	0.643	0.1	
POD12I	1.14	1.2	1.26	0.787	0.840	0.895	0.1	
POD12II	1.14	1.2	1.26	0.787	0.840	0.895	0.1	

1. V_{I_{CM}} is the input common mode voltage.
2. V_{I_D} is the input differential voltage.
3. V_{I_{CM}} rules are as follows:
 - a. V_{I_{CM}} must be less than V_{DDI} - 0.4V;
 - b. V_{I_{CM}} + V_{I_D}/2 must be < V_{DDI} + 0.4 V;
 - c. V_{I_{CM}} - V_{I_D}/2 must be > V_{SS} - 0.3 V.

Table 17 • Complementary Differential DC Output Levels

I/O Standard	V _{DDI} Min (V)	V _{DDI} Typ (V)	V _{DDI} Max (V)	V _{OL} Min (V)	V _{OL} Max (V)	V _{OH} ^{1,3} Min (V)	I _{OL} ² Min (mA)	I _{OH} ² Min (mA)
SSTL25I	2.375	2.5	2.625		V _{TT} – 0.608	V _{TT} + 0.608	8.1	8.1
SSTL25II	2.375	2.5	2.625		V _{TT} – 0.810	V _{TT} + 0.810	16.2	16.2
SSTL18I	1.71	1.8	1.89		V _{TT} – 0.603	V _{TT} + 0.603	6.7	6.7
SSTL18II	1.71	1.8	1.89		V _{TT} – 0.603	V _{TT} + 0.603	13.4	13.4
SSTL15I ⁴	1.425	1.5	1.575		0.2 × V _{DDI}	0.8 × V _{DDI}	V _{OL} /40	(V _{DDI} – V _{OH})/40
SSTL15II ⁴	1.425	1.5	1.575		0.2 × V _{DDI}	0.8 × V _{DDI}	V _{OL} /34	(V _{DDI} – V _{OH})/34
SSTL135I ⁴	1.283	1.35	1.418		0.2 × V _{DDI}	0.8 × V _{DDI}	V _{OL} /40	(V _{DDI} – V _{OH})/40
SSTL135II ⁴	1.283	1.35	1.418		0.2 × V _{DDI}	0.8 × V _{DDI}	V _{OL} /34	(V _{DDI} – V _{OH})/34
HSTL15I	1.425	1.5	1.575		0.4	V _{DDI} – 0.4	8	8
HSTL15II	1.425	1.5	1.575		0.4	V _{DDI} – 0.4	16	16
HSTL135I ⁴	1.283	1.35	1.418		0.2 × V _{DDI}	0.8 × V _{DDI}	V _{OL} /50	(V _{DDI} – V _{OH})/50
HSTL135II ⁴	1.283	1.35	1.418		0.2 × V _{DDI}	0.8 × V _{DDI}	V _{OL} /25	(V _{DDI} – V _{OH})/25
HSTL12I ⁴	1.14	1.2	1.26		0.1 × V _{DDI}	0.9 × V _{DDI}	V _{OL} /50	(V _{DDI} – V _{OH})/50
HSUL18I ⁴	1.71	1.8	1.89		0.1 × V _{DDI}	0.9 × V _{DDI}	V _{OL} /55	(V _{DDI} – V _{OH})/55
HSUL18II ⁴	1.71	1.8	1.89		0.1 × V _{DDI}	0.9 × V _{DDI}	V _{OL} /25	(V _{DDI} – V _{OH})/25
HSUL12I ⁴	1.14	1.2	1.26		0.1 × V _{DDI}	0.9 × V _{DDI}	V _{OL} /40	(V _{DDI} – V _{OH})/40
POD12I ^{3,4}	1.14	1.2	1.26		0.5 × V _{DDI}		V _{OL} /48	(V _{DDI} – V _{OH})/48
POD12II ^{3,4}	1.14	1.2	1.26		0.5 × V _{DDI}		V _{OL} /34	(V _{DDI} – V _{OH})/34

1. V_{OH} is the single-ended high-output voltage.
2. The total DC sink/source current of all IOs within a lane is limited as follows:
 - a. HSIO lane: 120 mA per 12 IO buffers.
 - b. GPIO lane: 160 mA per 12 IO buffers
3. V_{OH_MAX} based on external pull-up termination (pseudo-open drain).
4. I_{OL}/I_{OH} units for impedance standards in amps (not mA).

6.3.4 HSIO On-Die Termination

The following tables lists the on-die termination calibration accuracy specifications for HSIO bank.

Table 18 • Single-Ended Thevenin Termination (Internal Parallel Thevenin Termination)

Min (%)	Typ	Max (%)	Unit	Condition
-40	50	20	Ω	V _{DDI} = 1.8 V/1.5 V/1.35 V/1.2 V
-40	75	20	Ω	V _{DDI} = 1.8 V
-40	150	20	Ω	V _{DDI} = 1.8 V
-20	20	20	Ω	V _{DDI} = 1.5 V/1.35 V
-20	30	20	Ω	V _{DDI} = 1.5 V/1.35 V
-20	40	20	Ω	V _{DDI} = 1.5 V/1.35 V
-20	60	20	Ω	V _{DDI} = 1.5 V/1.35 V
-20	120	20	Ω	V _{DDI} = 1.5 V/1.35 V

Parameter	Description	Min (%)	Typ	Max (%)	Unit	Condition
Single-ended termination to V _{ss} ^{4,5}	Internal parallel termination to V _{ss}	-20	120	20	Ω	V _{DDI} = 2.5 V/1.8 V/1.5 V/1.2 V
		-20	240	20	Ω	V _{DDI} = 2.5 V/1.8 V/1.5 V/1.2 V

1. Measured across P to N with 400 mV bias.
2. Thevenin impedance is calculated based on independent P and N as measured at 50% of V_{DDI}.
3. For 50 Ω/75 Ω/150 Ω cases, nearest supported values of 40 Ω/60 Ω/120 Ω are used.
4. Measured at 50% of V_{DDI}.
5. Supported terminations vary with the IO type regardless of V_{DDI} nominal voltage. Refer to Libero for available combinations.

7 AC Switching Characteristics

This section contains the AC switching characteristics of the PolarFire FPGA device.

7.1 I/O Standards Specifications

This section describes I/O delay measurement methodology, buffer speed, switching characteristics, digital latency, gearing training calibration, and maximum physical interface (PHY) rate for memory interface IP.

7.1.1 Input Delay Measurement Methodology Maximum PHY Rate for Memory Interface IP

The following table provides information about the methodology for input delay measurement.

Table 22 • Input Delay Measurement Methodology

Standard	Description	V_L^1	V_H^1	V_{IP}^2	V_{ICM}^2	$V_{MEAS}^{3,4}$	$V_{REF}^{1,5}$	Unit
PCI	PCIE 3.3 V	0		VDDI		VDDI/2		V
LVTTL33	LVTTL 3.3 V	0		VDDI		VDDI/2		V
LVCMOS33	LVCMOS 3.3 V	0		VDDI		VDDI/2		V
LVCMOS25	LVCMOS 2.5 V	0		VDDI		VDDI/2		V
LVCMOS18	LVCMOS 1.8 V	0		VDDI		VDDI/2		V
LVCMOS15	LVCMOS 1.5 V	0		VDDI		VDDI/2		V
LVCMOS12	LVCMOS 1.2 V	0		VDDI		VDDI/2		V
SSTL25I	SSTL 2.5 V	$V_{REF} -$	$V_{REF} +$			V_{REF}	1.25	V
	Class I	0.5	0.5					
SSTL25II	SSTL 2.5 V	$V_{REF} -$	$V_{REF} +$			V_{REF}	1.25	V
	Class II	0.5	0.5					
SSTL18I	SSTL 1.8 V	$V_{REF} -$	$V_{REF} +$			V_{REF}	0.90	V
	Class I	0.5	0.5					
SSTL18II	SSTL 1.8 V	$V_{REF} -$	$V_{REF} +$			V_{REF}	0.90	V
	Class II	0.5	0.5					
SSTL15I	SSTL 1.5 V	$V_{REF} -$	$V_{REF} +$			V_{REF}	0.75	V
	Class I	.175	.175					
SSTL15II	SSTL 1.5 V	$V_{REF} -$	$V_{REF} +$			V_{REF}	0.75	V
	Class II	.175	.175					
SSTL135I	SSTL 1.35 V	$V_{REF} -$	$V_{REF} +$			V_{REF}	0.675	V
	Class I	.16	.16					
SSTL135II	SSTL 1.35 V	$V_{REF} -$	$V_{REF} +$			V_{REF}	0.675	V
	Class II	.16	.16					
HSTL15I	HSTL 1.5 V	$V_{REF} -$	$V_{REF} +$			V_{REF}	0.75	V
	Class I	.5	.5					
HSTL15II	HSTL 1.5 V	$V_{REF} -$	$V_{REF} +$			V_{REF}	0.75	V
	Class II	.5	.5					
HSTL135I	HSTL 1.35 V	$V_{REF} -$	$V_{REF} + .$			V_{REF}	0.675	V
	Class I	0.45	45					
HSTL135II	HSTL 1.35 V	$V_{REF} -$	$V_{REF} + .$			V_{REF}	0.675	V
	Class II	.45	.45					
HSTL12	HSTL 1.2 V	$V_{REF} -$	$V_{REF} + .$			V_{REF}	0.60	V
		.4	.4					

Standard	Description	V _L ¹	V _H ¹	V _{ID} ²	V _{ICM} ²	V _{MEAS} ^{3, 4}	V _{REF} ^{1, 5}	Unit
HSTL135II	Differential HSTL 1.35 V Class II	V _{ICM} – .125	V _{ICM} + .125	0.250	0.675	0		V
HSTL12	Differential HSTL 1.2 V	V _{ICM} – .125	V _{ICM} + .125	0.250	0.600	0		V
HSUL18I	Differential HSUL 1.8 V Class I	V _{ICM} – .125	V _{ICM} + .125	0.250	0.900	0		V
HSUL18II	Differential HSUL 1.8 V Class II	V _{ICM} – .125	V _{ICM} + .125	0.250	0.900	0		V
HSUL12	Differential HSUL 1.2 V	V _{ICM} – .125	V _{ICM} + .125	0.250	0.600	0		V
POD12I	Differential POD 1.2 V Class I	V _{ICM} – .125	V _{ICM} + .125	0.250	0.600	0		V
POD12II	Differential POD 1.2 V Class II	V _{ICM} – .125	V _{ICM} + .125	0.250	0.600	0		V
MIPI25	Mobile Industry Processor Interface	V _{ICM} – .125	V _{ICM} + .125	0.250	0.200	0		V

1. Measurements are made at typical, minimum, and maximum V_{REF} values. Reported delays reflect worst-case of these measurements. V_{REF} values listed are typical. Input waveform switches between V_L and V_H. All rise and fall times must be 1 V/ns.
2. Differential receiver standards all use 250 mV V_{ID} for timing. V_{CM} is different between different standards.
3. Input voltage level from which measurement starts.
4. The value given is the differential input voltage.
5. This is an input voltage reference that bears no relation to the V_{REF}/V_{MEAS} parameters found in IBIS models or shown in [Output Delay Measurement—Single-Ended Test Setup \(see page 27\)](#).
6. Emulated bi-directional interface.

7.1.2 Output Delay Measurement Methodology

The following section provides information about the methodology for output delay measurement.

Table 23 • Output Delay Measurement Methodology

Standard	Description	R _{REF} (Ω)	C _{REF} (pF)	V _{MEAS} (V)	V _{REF} (V)
PCI	PCIE 3.3 V	25	10	1.65	
LVTTL33	LVTTL 3.3 V	1M	0	1.65	
LVCMOS33	LVCMOS 3.3 V	1M	0	1.65	
LVCMOS25	LVCMOS 2.5 V	1M	0	1.25	
LVCMOS18	LVCMOS 1.8 V	1M	0	0.90	
LVCMOS15	LVCMOS 1.5 V	1M	0	0.75	
LVCMOS12	LVCMOS 1.2 V	1M	0	0.60	
SSTL25I	Stub-series terminated logic 2.5 V Class I	50	0	V _{REF}	1.25
SSTL25II	SSTL 2.5 V Class II	50	0	V _{REF}	1.25

Standard	STD	-1	Unit
LVC MOS12 (8 mA)	250	300	Mbps

Table 27 • GPIO Maximum Output Buffer Speed

Standard	STD	-1	Unit
LVDS25/LCMDS25	1250	1250	Mbps
LVDS33/LCMDS33	1250	1600	Mbps
RS DS25	800	800	Mbps
MINILVDS25	800	800	Mbps
SUBLVDS25	800	800	Mbps
PP DS25	800	800	Mbps
SLVSE15	500	500	Mbps
BUSLVDSE25	500	500	Mbps
MLVDSE25	500	500	Mbps
LVPECL E33	500	500	Mbps
SSTL25I	800	800	Mbps
SSTL25II	800	800	Mbps
SSTL25I (differential)	800	800	Mbps
SSTL25II (differential)	800	800	Mbps
SSTL18I	800	800	Mbps
SSTL18II	800	800	Mbps
SSTL18I (differential)	800	800	Mbps
SSTL18II (differential)	800	800	Mbps
SSTL15I	800	1066	Mbps
SSTL15II	800	1066	Mbps
SSTL15I (differential)	800	1066	Mbps
SSTL15II (differential)	800	1066	Mbps
HSTL15I	900	900	Mbps
HSTL15II	900	900	Mbps
HSTL15I (differential)	900	900	Mbps
HSTL15II (differential)	900	900	Mbps
HSUL18I	400	400	Mbps
HSUL18II	400	400	Mbps
HSUL18I (differential)	400	400	Mbps
HSUL18II (differential)	400	400	Mbps
PCI	500	500	Mbps
LV TTL33 (20 mA)	500	500	Mbps
LVC MOS33 (20 mA)	500	500	Mbps
LVC MOS25 (16 mA)	500	500	Mbps
LVC MOS18 (12 mA)	500	500	Mbps
LVC MOS15 (10 mA)	500	500	Mbps
LVC MOS12 (8 mA)	250	300	Mbps
MIPIE25	500	500	Mbps

Parameter	Symbol	Min	Typ	Max	Unit
Operating current (V_{DD1S})	RC_{SCVPP}			0.1	μA
Operating current (V_{DD})	RC_{SCVDD}			60.7	μA

7.3.2 SRAM Blocks

The following tables describe the LSRAM blocks' performance.

Table 43 • LSRAM Performance Industrial Temperature Range (−40 °C to 100 °C)

Parameter	V _{DD} = 1.0 V – STD	V _{DD} = 1.0 V – 1	V _{DD} = 1.05 V – STD	V _{DD} = 1.05 V – 1	Unit	Condition
Operating frequency	343	428	343	428	MHz	Two-port, all supported widths, pipelined, simple-write, and write-feed-through
	309	428	309	428	MHz	Two-port, all supported widths, non-pipelined, simple-write, and write-feed-through
	343	428	343	428	MHz	Dual-port, all supported widths, pipelined, simple-write, and write-feed-through
	309	428	309	428	MHz	Dual-port, all supported widths, non-pipelined, simple-write, and write-feed-through
	343	428	343	428	MHz	Two-port pipelined ECC mode, pipelined, simple-write, and write-feed-through
	279	295	279	295	MHz	Two-port non-pipelined ECC mode, pipelined, simple-write, and write-feed-through
	343	428	343	428	MHz	Two-port pipelined ECC mode, non-pipelined, simple-write, and write-feed-through
	196	285	196	285	MHz	Two-port non-pipelined ECC mode, non-pipelined, simple-write, and write-feed-through
	274	285	274	285	MHz	Two-port, all supported widths, pipelined, and read-before-write
	274	285	274	285	MHz	Two-port, all supported widths, non-pipelined, and read-before-write
	274	285	274	285	MHz	Dual-port, all supported widths, pipelined, and read-before-write
	274	285	274	285	MHz	Dual-port, all supported widths, non-pipelined, and read-before-write
	274	285	274	285	MHz	Two-port pipelined ECC mode, pipelined, and read-before-write
	274	285	274	285	MHz	Two-port non-pipelined ECC mode, pipelined, and read-before-write
	274	285	274	285	MHz	Two-port pipelined ECC mode, non-pipelined, and read-before-write
	193	285	193	285	MHz	Two-port non-pipelined ECC mode, non-pipelined, and read-before-write

Parameter	Symbol	STD Min	STD Typ	STD Max	-1 Min	-1 Typ	-1 Max	Unit
Reference clock input rate ^{1, 2, 3}	$F_{XCVREFCLKMAX}$ CASCADE	20		156	20		156	MHz
Reference clock rate at the PFD ⁴	$F_{TXREFCLKPFD}$	20		156	20		156	MHz
Reference clock rate recommended at the PFD for Tx rates 10 Gbps and above ⁴	$F_{TXREFCLKPFD10G}$	75		156	75		156	MHz
Tx reference clock phase noise requirements to meet jitter specifications (156 MHz clock at reference clock input) ⁵	$F_{TXREFPN}$				-110		-110	dBc /Hz
Phase noise at 10 KHz	$F_{TXREFPN}$				-110		-110	dBc /Hz
Phase noise at 100 KHz	$F_{TXREFPN}$				-115		-115	dBc /Hz
Phase noise at 1 MHz	$F_{TXREFPN}$				-135		-135	dBc /Hz
Reference clock input rise time (10%–90%)	$T_{REFRISE}$		200	500		200	500	ps
Reference clock input fall time (90%–10%)	$T_{REFFALL}$		200	500		200	500	ps
Reference clock duty cycle	$T_{REFDUTY}$	40		60	40		60	%
Spread spectrum modulation spread ⁶	Mod_Spread	0.1		3.1	0.1		3.1	%
Spread spectrum modulation frequency ⁷	Mod_Freq	TxREF CLKPFD/ (128)	32	TxREF CLKPFD/ (128*63)	32	TxREF CLKPFD/ (128)		KHz

1. See the maximum reference clock rate allowed per input buffer standard.
2. The minimum value applies to this clock when used as an XCVR reference clock. It does not apply when used as a non-XCVR input buffer (DC input allowed).
3. Cascaded reference clock.
4. After reference clock input divider.
5. Required maximum phase noise is scaled based on actual $F_{TxRefClkPFD}$ value by $20 \times \log_{10} (TxRefClkPFD / 156 \text{ MHz})$. It is assumed that the reference clock divider of 4 is used for these calculations to always meet the maximum PFD frequency specification.
6. Programmable capability for depth of down-spread or center-spread modulation.
7. Programmable modulation rate based on the modulation divider setting (1 to 63).

7.4.3

Transceiver Reference Clock I/O Standards

The following table describes the differential I/O standards supported as transceiver reference clocks.

Parameter	Symbol	Min	Typ	Max	Unit	Condition
		0.41			UI	>3.2–8.5 Gbps ⁵
		0.41			UI	>1.6 to 3.2 Gbps ⁵
		0.41			UI	>0.8 to 1.6 Gbps ⁵
		0.41			UI	250 to 800 Mpbs ⁵
Total jitter tolerance with stressed eye	T _{JTOLSE}	0.65			UI	3.125 Gbps ⁵
		0.65			UI	6.25 Gbps ⁶
		0.7			UI	10.3125 Gbps ⁶
					UI	12.7 Gbps ^{6, 10}
Sinusoidal jitter tolerance with stressed eye	T _{SJOLSE}	0.1			UI	3.125 Gbps ⁵
		0.05			UI	6.25 Gbps ⁶
		0.05			UI	10.3125 Gbps ⁶
					UI	12.7 Gbps ^{6, 10}
CTLE DC gain (all stages, max settings)				10	dB	
CTLE AC gain (all stages, max settings)				16	dB	
DFE AC gain (per 5 stages, max settings)				7.5	dB	

1. Valid at 3.2 Gbps and below.
2. Data vs. Rx reference clock frequency.
3. Achieves compliance with PCIe electrical idle detection.
4. Achieves compliance with SATA OOB specification.
5. Rx jitter values based on bit error ratio (BER) of 10–12, AC coupled input with 400 mV V_{ID}, all stages of Rx CTLE enabled, DFE disabled, 80 MHz sinusoidal jitter injected to Rx data.
6. Rx jitter values based on bit error ratio (BER) of 10–12, AC coupled input with 400 mV V_{ID}, all stages of Rx CTLE enabled, DFE enabled, 80 MHz sinusoidal jitter injected to Rx data.
7. For PCIe: Low Threshold Setting = 1, High Threshold Setting = 2.
8. For SATA: Low Threshold Setting = 2, High Threshold Setting = 3.
9. Loss of signal detection is valid for input signals that transition at a density ≥ 1 Gbps for PRBS7 data or 6 Gbps for PRBS31 data.
10. For data rates greater than 10.3125 Gbps, VDDA must be set to 1.05 V mode. See supply tolerance in the section [Recommended Operating Conditions \(see page 6\)](#).

7.5 Transceiver Protocol Characteristics

The following section describes transceiver protocol characteristics.

7.5.1 PCI Express

The following tables describe the PCI express.

Table 54 • PCI Express Gen1

Parameter	Data Rate	Min	Max	Unit
Total transmit jitter	2.5 Gbps	0.25		UI
Receiver jitter tolerance	2.5 Gbps	0.4		UI

Note: With add-in card, as specified in PCI Express CEM Rev 2.0.

Table 60 • 10GbE (RXAUI)

	Data Rate	Min	Max	Unit
Total transmit jitter	6.25 Gbps			UI
Receiver jitter tolerance	6.25 Gbps			UI

7.5.4 1GbE (1000BASE-T)

The following table describes 1GbE (1000BASE-T).

Table 61 • 1GbE (1000BASE-T)

	Data Rate	Min	Max	Unit
Total transmit jitter	1.25 Gbps			UI
Receiver jitter tolerance	1.25 Gbps			UI

The following table describes 1GbE (1000BASE-X).

Table 62 • 1GbE (1000BASE-X)

	Data Rate	Min	Max	Unit
Total transmit jitter	1.25 Gbps			UI
Receiver jitter tolerance	1.25 Gbps			UI

7.5.5 SGMII and QSGMII

The following table describes SGMII.

Table 63 • SGMII

Parameter	Data Rate	Min	Max	Unit
Total transmit jitter	1.25 Gbps		0.24	UI
Receiver jitter tolerance	1.25 Gbps	0.749		UI

The following table describes QSGMII.

Table 64 • QSGMII

Parameter	Data Rate	Min	Max	Unit
Total transmit jitter	5.0 Gbps		0.3	UI
Receiver jitter tolerance	5.0 Gbps	0.65		UI

7.5.6 SDI

The following table describes SDI.

Table 65 • SDI

Parameter	Data Rate	Min	Max	Unit
Total transmit jitter				UI
Receiver jitter tolerance				UI

Parameter	Typ	Max	Unit	Conditions
Time to destroy data in non-volatile memory (recoverable) ^{1,3}			ms	One iteration of scrubbing
Time to destroy data in non-volatile memory (non-recoverable) ^{1,4}			ms	One iteration of scrubbing
Time to scrub the fabric data ¹			s	Full scrubbing
Time to scrub the pNVM data (like new) ^{1,2}			s	Full scrubbing
Time to scrub the pNVM data (recoverable) ^{1,3}			s	Full scrubbing
Time to scrub the fabric data pNVM data (non-recoverable) ^{1,4}			s	Full scrubbing
Time to verify ⁵			s	

1. Total completion time after interning zeroization.
2. Like new mode—zeroizes user design security setting and sNVM content.
3. Recoverable mode—zeroizes user design security setting, sNVM and factory keys.
4. Non-recoverable mode—zeroizes user design security setting, sNVM and factory keys, and factory data required for programming.
5. Time to verify after scrubbing completes.

Table 79 • Zeroization Times for MPF300T, TL, TS, and TLS Devices

Parameter	Typ	Max	Unit	Conditions
Time to enter zeroization			ms	Zip flag set
Time to destroy the fabric data ¹			ms	Data erased
Time to destroy data in non-volatile memory (like new) ^{1,2}			ms	One iteration of scrubbing
Time to destroy data in non-volatile memory (recoverable) ^{1,3}			ms	One iteration of scrubbing
Time to destroy data in non-volatile memory (non-recoverable) ^{1,4}			ms	One iteration of scrubbing
Time to scrub the fabric data ¹			s	Full scrubbing
Time to scrub the pNVM data (like new) ^{1,2}			s	Full scrubbing
Time to scrub the pNVM data (recoverable) ^{1,3}			s	Full scrubbing
Time to scrub the fabric data pNVM data (non-recoverable) ^{1,4}			s	Full scrubbing
Time to verify ⁵			s	

1. Total completion time after interning zeroization.
2. Like new mode—zeroizes user design security setting and sNVM content.
3. Recoverable mode—zeroizes user design security setting, sNVM and factory keys.
4. Non-recoverable mode—zeroizes user design security setting, sNVM and factory keys, and factory data required for programming.
5. Time to verify after scrubbing completes.

Table 80 • Zeroization Times for MPF500T, TL, TS, and TLS Devices

Parameter	Typ	Max	Unit	Conditions
Time to enter zeroization			ms	Zip flag set
Time to destroy the fabric data ¹			ms	Data erased
Time to destroy data in non-volatile memory (like new) ^{1,2}			ms	One iteration of scrubbing
Time to destroy data in non-volatile memory (recoverable) ^{1,3}			ms	One iteration of scrubbing

Parameter	Type	Max	Unit	Conditions
Time to destroy data in non-volatile memory (non-recoverable) ^{1,4}		ms		One iteration of scrubbing
Time to scrub the fabric data ¹		s		Full scrubbing
Time to scrub the pNVM data (like new) ^{1,2}		s		Full scrubbing
Time to scrub the pNVM data (recoverable) ^{1,3}		s		Full scrubbing
Time to scrub the fabric data pNVM data (non-recoverable) ¹		s		Full scrubbing
Time to verify ⁵		s		

1. Total completion time after entering zeroization.
2. Like new mode—zeroizes user design security setting and sNVM content.
3. Recoverable mode—zeroizes user design security setting, sNVM and factory keys.
4. Non-recoverable mode—zeroizes user design security setting, sNVM and factory keys, and factory data required for programming.
5. Time to verify after scrubbing completes.

7.6.7 Verify Time

The following tables describe verify time.

Table 81 • Standalone Fabric Verify Times

Parameter	Devices	Max	Unit
Standalone verification over JTAG	MPF100T, TL, TS, TLS		s
	MPF200T, TL, TS, TLS	53 ¹	s
	MPF300T, TL, TS, TLS	90 ¹	s
	MPF500T, TL, TS, TLS		s
Standalone verification over SPI	MPF100T, TL, TS, TLS		s
	MPF200T, TL, TS, TLS	37 ²	s
	MPF300T, TL, TS, TLS	55 ²	s
	MPF500T, TL, TS, TLS		s

1. Programmer: FlashPro5, TCK 10 MHz; PC configuration: Intel i7 at 3.6 GHz, 32 GB RAM, Windows 10.
2. SmartFusion2 with MSS running at 100 MHz, MSS_SPI_0 port running at 6.67 MHz. DirectC version 4.1.

Notes:

- Standalone verify is limited to 2,000 total device hours over the industrial –40 °C to 100 °C temperature.
- Use the digest system service, for verify device time more than 2,000 hours.
- Standalone verify checks the programming margin on both the P and N gates of the push-pull cell.
- Digest checks only the P side of the push-pull gate. However, the push-pull gates work in tandem. Digest check is recommended if users believe they will exceed the 2,000-hour verify time specification.

Table 82 • Verify Time by Programming Hardware

Devices	IAP	FlashPro4	FlashPro5	BP	Silicon Sculptor	Units
MPF100T, TL, TS, TLS						
MPF200T, TL, TS, TLS	9	67	53			s
MPF300T, TL, TS, TLS	14	95	90			s

Devices	IAP	FlashPro4	FlashPro5	BP	Silicon Sculptor	Units
MPF500T, TL, TS, TLS						

Notes:

- FlashPro4 4 MHz TCK.
- FlashPro5 10 MHz TCK.
- PC configuration: Intel i7 at 3.6 GHz, 32 GB RAM, Windows 10.

Table 83 • Verify System Services

Parameter	Symbol	ServiceID	Devices	Typ	Max	Unit
In application verify by index	T _{IAP_Ver_Index}	44H	MPF100T, TL, TS, TLS			s
			MPF200T, TL, TS, TLS	8.2	9	s
			MPF300T, TL, TS, TLS	12.4	13	s
			MPF500T, TL, TS, TLS			s
In application verify by SPI address	T _{IAP_Ver_Addr}	45H	MPF100T, TL, TS, TLS			s
			MPF200T, TL, TS, TLS	8.2	9	s
			MPF300T, TL, TS, TLS	12.4	13	s
			MPF500T, TL, TS, TLS			s

7.6.8 Authentication Time

The following tables describe authentication system service time.

Table 84 • Authentication Services

Parameter	Symbol	ServiceID	Devices	Typ	Max	Unit
Bitstream Authentication	T _{BIT_AUTH}	22H	MPF100T, TL, TS, TLS			s
			MPF200T, TL, TS, TLS	3.3	3.7	s
			MPF300T, TL, TS, TLS	4.9	5.4	s
			MPF500T, TL, TS, TLS			s
IAP Image Authentication	T _{IAP_AUTH}	23H	MPF100T, TL, TS, TLS			s
			MPF200T, TL, TS, TLS	3.3	3.7	s
			MPF300T, TL, TS, TLS	4.9	5.4	s
			MPF500T, TL, TS, TLS			s

7.6.9 Secure NVM Performance

The following table describes secure NVM performance.

Table 85 • sNVM Read/Write Characteristics

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Plain text programming		7.0	7.2	7.9	ms	
Authenticated text programming		7.2	7.4	9.4	ms	
Authenticated and encrypted text programming		7.2	7.4	9.4	ms	
Authentication R/W 1st access from power-up overhead	T _{PUF_OVHD}		100	111	ms	From T _{FAB_READY}
Plain text read		7.67	7.79	8.2	μs	

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Authenticated text read		113.25	114.02	118.5	μs	
Authenticated and decrypted text read		159.59	160.53	166.5	μs	

Notes:

- Page size= 252 bytes (non-authenticated), 236 bytes (authenticated).
- Only page reads and writes allowed.
- T_{PUF_OVHD} is an additional time that occurs on the first R/W, after cold or warm boot, to sNVM using authenticated or encrypted text.

7.6.10 Secure NVM Programming Cycles

The following table describes secure NVM programming cycles.

Table 86 • sNVM Programming Cycles vs. Retention Characteristics

Programming Temperature	Programming Cycles per Page, Max	Programming Cycles per Block, Max	Retention Years
-40 °C to 100 °C	10,000	100,000	20
-40 °C to 85 °C	10,000	100,000	20
-40 °C to 55 °C	10,000	100,000	20

Note: Page size = 128 bytes. Block size = 56 KBytes.

7.7 System Services

This section describes system switching and throughput characteristics.

7.7.1 System Services Throughput Characteristics

The following table describes system services throughput characteristics.

Table 87 • System Services Throughput Characteristics

Parameter	Symbol	Service ID	Typ	Max	Unit	Conditions
Serial number	T_{Serial}	00H	65	67	μs	
User code	T_{User}	01H	0.8	1.05	μs	
Design information	T_{Design}	02H	2.4	2.7	μs	
Device certificate	T_{Cert}	03H	255	271	ms	
Read digests	T_{digest_read}	04H	201	215	μs	
Query security locks	T_{sec_Query}	05H	15	17	μs	
Read debug information	T_{Rd_debug}	06H	34	38	μs	
Reserved		07H–0FH				
Secure NVM write plain text	$T_{SNVM_Wr_Plain}$	10H				Note 1
Secure NVM write authenticated plain text	$T_{SNVM_Wr_Auth}$	11H				Note 1
Secure NVM write authenticated cipher text	$T_{SNVM_Wr_Cipher}$	12H				Note 1
Reserved		13H–17H				

ECDSA SigVer, P-384/SHA-384	1024 8K	6421841 6273510	5759 5759
Key Agreement (KAS), P-384		5039125	6514
Point Multiply, P-256 ¹		5176923	4482
Point Multiply, P-384 ¹		12043199	5319
Point Multiply, P-521 ¹		26887187	6698
Point Addition, P-384		3018067	5779
KeyGen (PKG), P-384		12055368	6908
Point Verification, P-384		5091	3049

1. With DPA counter measures.

Table 120 • IFC (RSA)

Modes	Message Size (bits)	Athena TeraFire Crypto Core Clock-Cycles	CAL Delay In CPU Clock-Cycles
Encrypt, RSA-2048, e=65537	2048	436972	8,972
Encrypt, RSA-3072, e=65537	3072	962162	12,583
Decrypt, RSA-2048 ¹ , CRT	2048	26862392	15900
Decrypt, RSA-3072 ¹ , CRT	3072	75153782	22015
Decrypt, RSA-4096, CRT	4096	89235615	23710
Decrypt, RSA-3072, CRT	3072	37880180	18638
SigGen, RSA-3072/SHA-384 ¹ ,CRT, PKCS #1 V 1.5	1024 8K	75197644 75213653	20032 19303
SigGen, RSA-3072/SHA-384, PKCS #1, V 1.5	1024 8K	148090970 148102576	14642 13936
SigVer, RSA-3072/SHA-384, e = 65537, PKCS #1 V 1.5	1024 8K	970991 982011	12000 11769
SigVer, RSA-2048/SHA-256, e = 65537, PKCS #1 V 1.5	1024 8K	443493 453007	8436 8436
SigGen, RSA-3072/SHA-384, ANSI X9.31	1024 8K	147138254 147155896	13945 13523
SigVer, RSA-3072/SHA-384, e = 65537, ANSI X9.31	1024 8K	973269 983255	11313 11146

1. With DPA counter measures.

Table 121 • FFC (DH)

Modes	Message Size (bits)	Athena TeraFire Crypto Core Clock-Cycles	CAL Delay In CPU Clock-Cycles
SigGen, DSA-3072/SHA-384 ¹	1024 8K	27932907 27942415	13969 13501
SigGen, DSA-3072/SHA-384	1024	12086356	13602
SigVer, DSA-3072/SHA-384	1024 8K	24597916 24229420	15662 15133



a  **MICROCHIP** company

Microsemi Headquarters

One Enterprise, Aliso Viejo,
CA 92656 USA
Within the USA: +1 (800) 713-4113
Outside the USA: +1 (949) 380-6100
Sales: +1 (949) 380-6136
Fax: +1 (949) 215-4996
Email: sales.support@microsemi.com
www.microsemi.com

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